NSN 5961-01-155-0846 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic
Overall Length:
Between 0.515 inches and 0.565 inches
Overall Diameter:
Between 1.600 inches and 1.656 inches
Mounting Method:
Compression
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 repetitive peak off-state voltage and 300.0 repetitive peak reverse voltage and 400.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
3500.00 amperes peak forward surge current nanoamperes
Power Rating Per Characteristic:
10.0 watts small-signal input power, common-collector blank and 2.0 watts small-signal input power, common-collector universa
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
2 case and 1 quick disconnect, male and 1 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0